

■特征 Features

- I_o 2A
- V_{RRM} 50V~1000V
- 玻璃钝化芯片
Glass passivated chip
- 耐正向浪涌电流能力高
High surge forward current capability

■用途 Applications

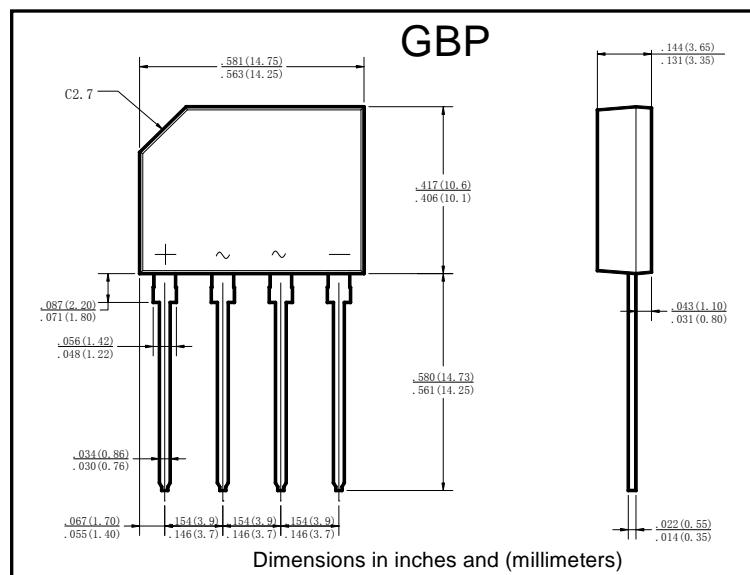
- 作一般电源单相桥式整流用
General purpose 1 phase Bridge rectifier applications

■极限值（绝对最大额定值）
Limiting Values (Absolute Maximum Rating)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	GBP2							
				005	01	02	04	06	08	10	
反向重复峰值电压 Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	200	400	600	800	1000	
平均整流输出电流 Average Rectified Output Current	I_o	A	60Hz正弦波, 电阻负载 60Hz sine wave, R-load	Without heatsink $T_c=70^\circ\text{C}$							
			$T_c=140^\circ\text{C}$	With heatsink $T_c=140^\circ\text{C}$							
正向(不重复)浪涌电流 Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz正弦波, 一个周期, $T_j=25^\circ\text{C}$ 60Hz sine wave, 1 cycle, $T_j=25^\circ\text{C}$	60							
正向浪涌电流的平方对电流 浪涌持续时间的积分值 Current Squared Time	I^2t	A^2s	$1\text{ms} \leq t < 8.3\text{ms}$ $T_j=25^\circ\text{C}$, 单个二极管 $1\text{ms} \leq t < 8.3\text{ms}$ $T_j=25^\circ\text{C}$, Rating of per diode	17							
存储温度 Storage Temperature	T_{stg}	$^\circ\text{C}$		-55 ~ +150							
结温 Junction Temperature	T_j	$^\circ\text{C}$		-55 ~ +150							

■电特性 ($T_a=25^\circ\text{C}$ 除非另有规定)
Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测试条件 Test Condition	最大值 Max
正向峰值电压 Peak Forward Voltage	V_{FM}	V	$I_{FM}=1.0\text{A}$, 脉冲测试, 单个二极管的额定值 $I_{FM}=1.0\text{A}$, Pulse measurement, Rating of per diode	1.05
反向峰值电流 Peak Reverse Current	I_{RRM}	μA	$V_{RM}=V_{RRM}$, 脉冲测试, 单个二极管的额定值 $V_{RM}=V_{RRM}$, Pulse measurement, Rating of per diode	10
热阻 Thermal Resistance	$R_{\theta J-A}$	$^\circ\text{C}/\text{W}$	结和环境之间 Between junction and ambient	47
	$R_{\theta J-C}$		结和引线之间 Between junction and lead	10

■外形尺寸和印记 Outline Dimensions and Mark


■ 特性曲线 (典型) Characteristics(Typical)

